

PHD**D16A(K) 1K8VC...SERIES****STANDARD RECOVERY DIODES****Stud Version****Features**

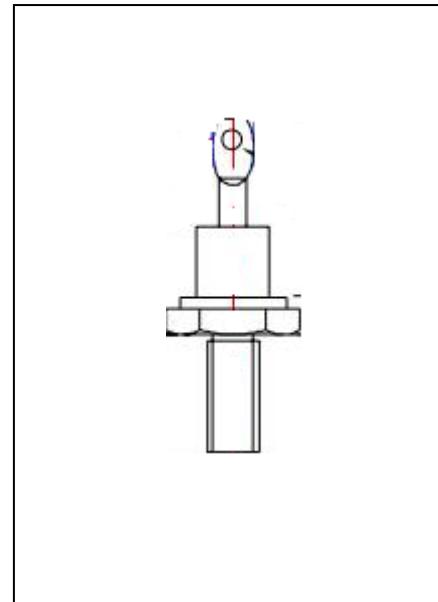
- Hermetic metal case with ceramic insulator
- Capacity of supporting High surge current
- Stud cathode and stud anode version

16A**Typical Applications**

- Converters
- Power supplies
- Machine tool controls

Major Ratings and Characteristics

Parameters	D16A(K) 1K8VC	Units
$I_{F(AV)}$	16	A
	@ T_{hs}	°C
$I_{F(RMS)}$	26	A
I_{FSM}	@ 50Hz	A
	@ 60Hz	A
$I^2 t$	@ 50Hz	$A^2 s$
	@ 60Hz	$A^2 s$
V_{RRM}	range	1000 to 1200
T_J	range	-65 to 175



PHD**D16A(K) 1K8VC...SERIES****ELECTRICAL SPECIFICATIONS****Voltage Ratings**

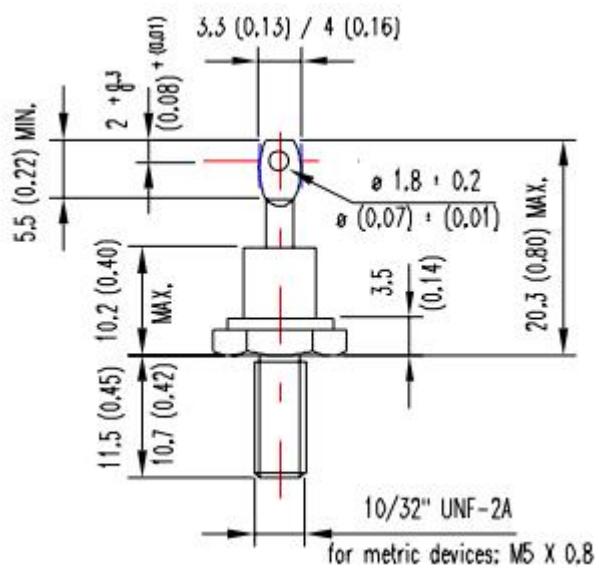
D16A(K)	Voltage Code	V_{RRM} , maximum repetitive peak reverse voltage V	V_{RSM} , maximum non- repetitive peak rev. voltage V	I_{RRM} max. @ $T_J = 175^\circ C$ mA
	10	1000	1100	12
18	1800	1900		

Forward Conduction

Parameter	D16 A(K)	Units	Conditions			
$I_{F(AV)}$	Max. average forward current @ Heatsink temperature	16	A	180° conduction, half sine wave Double side (single side) cooled		
		120	°C			
$I_{F(RMS)}$	Max.RMS forward current	26	A			
I_{FSM} ,	Max. peak, one-cycle forward, non-repetitive surge current	356	A	$t = 10ms$	No voltage reapplied	
		373		$t = 8.3ms$		
		300		$t = 10ms$	100% V_{RRM} reapplied	
		314		$t = 8.3ms$		
$I^2 t$	Maximum $I^2 t$ for fusing	636	$A^2 s$	$t = 10ms$	Sinusoidal half wave,Initial $T_J = T_J$ max.	
		580		$t = 8.3ms$		
		450		$t = 10ms$		
		410		$t = 8.3ms$		
		636		$t = 0.1$ to 10ms, no voltage reapplied		
$I^2 \sqrt{t}$	Maximum $I^2 \sqrt{t}$ for fusing	0				
V_{FM}	Max. forward voltage drop	1.30	V	$I_{pk} = 78A$, $T_J = 25^\circ C$, $t_p=400 \mu s$ rectangular wave		
$V_{F(TO)}$	Low level value of threshold voltage	0.8	V	$(16.7\% \times \pi \times I_{F(AV)} < 1 < \pi \times I_{F(AV)})$, $T_J=T_J$ max		
r_f	Low level value of forward slope resistance	6.8	MΩ	$(16.7\% \times \pi \times I_{F(AV)} < 1 < \pi \times I_{F(AV)})$, $T_J=T_J$ max		

Thermal and Mechanical Specification

Parameter	D16A(K)	Units	Conditions
T_J	Max.junction operating temperature range	-65 to 175	°C
T_{stg}	Max. storage temperature range	-65 to 200	
R_{thJC}	Max.thermal resistance,junction to case	1.5	K/W
R_{thCS}	Max. thermal resistance,Case to heatsink	0.5	
T	Max.allowed Mounting torque, ± 10%	7	N
wt	Approximate weight	11	g



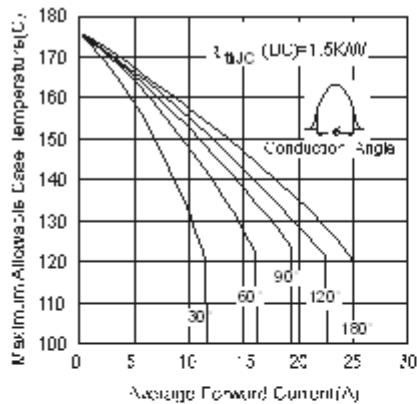


Fig.1-Current Ratings Characteristics

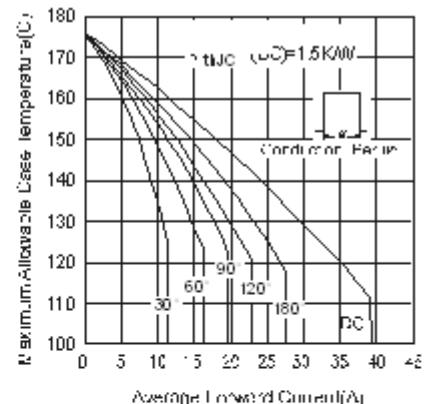


Fig.2-Current Ratings Characteristics

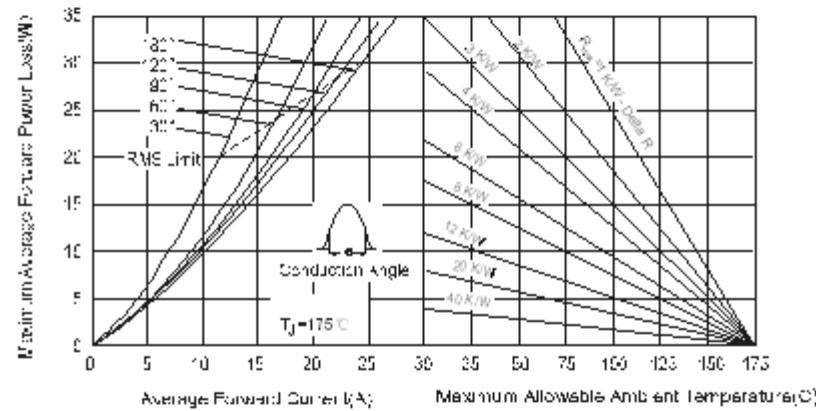


Fig.3-Forward Power Loss Characteristics

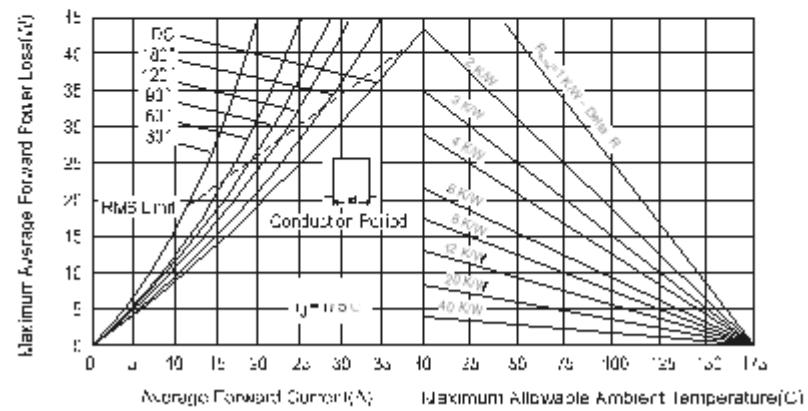


Fig.4-Forward Power Loss Characteristics

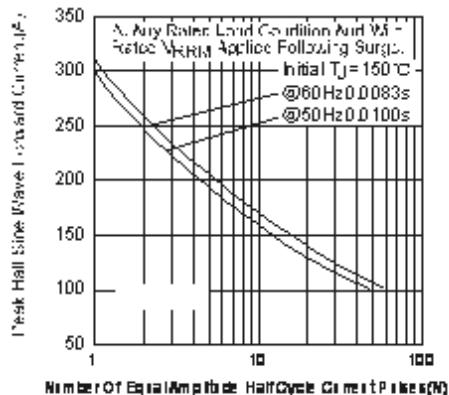


Fig.5-Maximum Non-Repetitive Surge Current

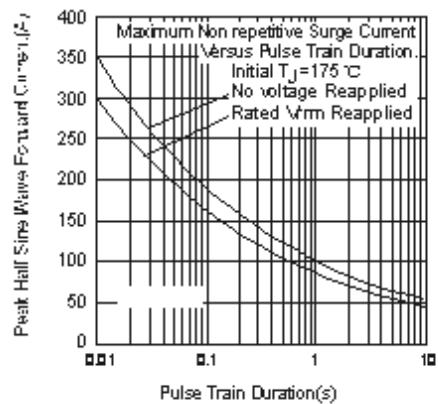


Fig.6-Maximum Non-Repetitive Surge Current

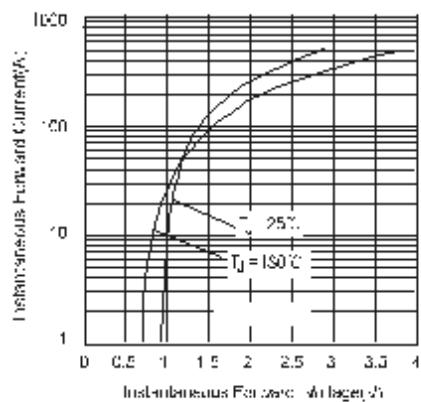
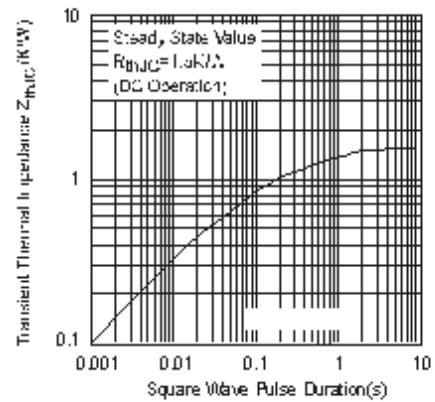


Fig.7-Forward Voltage Drop Characteristics

Fig.8-Thermal Impedance Z_{thic} Characteristics